

## 1024K (8 x 16K x 8) CMOS UV EPROM - OTP ROM

- PAGE ORGANIZED (M27128 FOOTPRINT).
- VERY FAST ACCESS TIME: 120 ns.
- COMPATIBLE TO HIGH SPEED.
- MICROPROCESSORS ZERO WAIT STATE LOW POWER "CMOS" CONSUMPTION:
  - Operating current 35 mA.
  - Stand by current 200 µA.
- PROGRAMMING VOLTAGE 12.75 V.
- ELECTRONIC SIGNATURE FOR AUTOMATED PROGRAMMING.
- PROGRAMMING TIMES OF AROUND 12 SECONDS (PRESTO II ALGORITHM).

## PRODUCT PREVIEW 28 1 FDIP28-W (Ordering information at the end of the datasheet)

## DESCRIPTION

The M27C1011 is a high speed 1,048,576 bit ultraviolet erasable and reprogrammable EPROM ideally suited for applications where fast turnaround and pattern experimentation are important requirements.

Its "PAGE-ORGANIZATION" (based on 16K x 8 module) allows an easy up-grading of applications, as foot-print and addressing mode remain constant.

It is housed in a 28 pin Window Ceramic Frit Seal package. The transparent lid allows the user to expose the chip to ultraviolet light to erase the bit pattern. A new pattern can then be written to the device by following the programming procedure.

## **PIN NAMES**

A0 - A13	ADDRESS INPUT
CE	CHIP ENABLE
OE	OUTPUT ENABLE
PGM/WE	PROGRAM/PAGE SELECT
O3 - O7	OUTPUT
D0/O0 - D2/O2	INPUT/OUTPUT
V <sub>PP</sub>	PROGRAMMING VOLTAGE
Vcc	+5V POWER SUPPLY
GND	GROUND

Figure 1 : Pin Configuration

Vpp	[ 1	<b>28</b> 🗓	Vcc
A12	2	27	PGM/WE
A7	3	26	Λ13
<b>A</b> 6	4	25	<b>A8</b>
<b>A</b> 5	5	24	A9
A4	[ 6	23	A11
A3	[ 7	22	OE
A2	8	21	A10
A1	9	20	CE
AO	10	19	07
$D_0/O_0$	11	18	06
D1/01	12	17	05
D <sub>2</sub> /O <sub>2</sub> GND	13 14	16 ] 15 ]	04 03
	1		00711